

OP07C, **OP07D** SLOS099F-OCTOBER 1979-REVISED JANUARY 2014

OP07x Precision Operational Amplifiers

Check for Samples: OP07C, OP07D

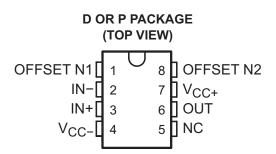
FEATURES

- Low Noise
- **No External Components Required**
- **Replace Chopper Amplifiers at a Lower Cost**
- Wide Input-Voltage Range: 0 to ±14 V Typ
- Wide Supply-Voltage Range: ±3 V to ±18 V

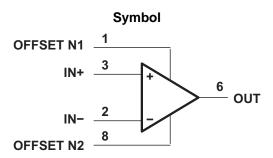
DESCRIPTION

These devices offer low offset and long-term stability by means of a low-noise, chopperless, bipolar-inputtransistor amplifier circuit. For most applications, external components are not required for offset nulling and frequency compensation. The true differential input, with a wide input-voltage range and outstanding common-mode rejection, provides maximum flexibility and performance in high-noise environments and in noninverting applications. Low bias currents and extremely high input impedances are maintained over the entire temperature range. The OP07 devices are unsurpassed for low-noise, high-accuracy amplification of very-low-level signals.

These devices are characterized for operation from 0°C to 70°C.



NC-No internal connection

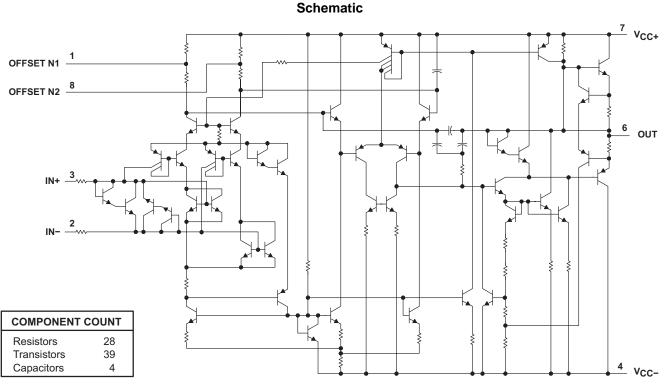


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TEXAS INSTRUMENTS

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Current values shown are nominal.



Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN MA	K UNIT
V _{CC+} ⁽²⁾	Supply veltage	2	2 V	
$V_{CC+}^{(2)}$ $V_{CC-}^{(2)}$	Supply voltage	-2		
	Differential input voltage ⁽³⁾	±3	V C	
VI	Input voltage range (either input) ⁽⁴⁾	±2	2 V	
	Duration of output short circuit ⁽⁵⁾	Unlimited		
0	Package thermal impedance, junction to free air ⁽⁶⁾⁽⁷⁾	D package	9	7 ℃/W
θ_{JA}	Fackage thermai impedance, junction to nee all (****	8	5	
TJ	Operating virtual-junction temperature	15	°C ℃	
	Lead temperature 1,6 mm (1/16 in) from case for 10 s		26	°C ℃
T _{stg}	Storage temperature range		-65 15	0°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltage values, unless otherwise noted, are with respect to the midpoint between V_{CC+} and V_{CC-} (2)

(3) Differential voltages are at IN+ with respect to IN-.

The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less. (4)

The output may be shorted to ground or to either power supply. (5)

- Maximum power dissipation is a function of $T_{J(max)}$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_{J(max)} T_A)/\theta_{JA}$. Selecting the maximum of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7. (6)
- (7)

Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC\pm}$	Supply voltage		±3	±18	V
V _{IC}	Common-mode input voltage	$V_{CC\pm} = \pm 15 V$	-13	13	V
T _A	Operating free-air temperature		0	70	°C

OP07C, OP07D

SLOS099F-OCTOBER 1979-REVISED JANUARY 2014

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ISTRUMENTS

EXAS

Electrical Characteristics

at specified free-air temperature, $V_{CC\pm} = \pm 15 \text{ V}$ (unless otherwise noted)⁽¹⁾

	PARAMETER	TEST CONDITIONS	T _A ⁽²⁾		OP07C			OP07D			
	PARAMETER	TEST CONDITIONS	IA(-/	MIN	TYP	MAX	MIN	MIN TYP MAX		UNIT	
	land offerstanding	N 0.V D 500	25°C		60				150		
V _{IO}	Input offset voltage	$V_{O} = 0 V$ $R_{S} = 50\Omega$	0°C to 70°C		85				250	μV	
α _{VIO}	Temperature coefficient of input offset voltage	$V_{O} = 0 V$ $R_{S} = 50\Omega$	0°C to 70°C		0.5				2.5	µV/°C	
	Long-term drift of input offset voltage	See ⁽³⁾			0.4					µV/mo	
	Offset adjustment range	$R_{S} = 20 \text{ k}\Omega$, See Figure 1	25°C		±4					mV	
	Input offset current		25°C		0.8				6	nA	
Ю	Input onset current		0°C to 70°C		1.6				8	ΠA	
α _{IIO}	Temperature coefficient of input offset current		0°C to 70°C		12				50	pA/°C	
B Input bias current		25°C		±1.8				±12	nA		
IB Input bias current			0°C to 70°C		±2.2				±14	ΠA	
α _{IIB}	Temperature coefficient of input bias current		0°C to 70°C		18				50	pA/°C	
V _{ICR}	Common-mode input		25°C	±13	±14		±13	±14		- V	
	voltage range		0°C to 70°C	±13	±13.5		±13	±13.5			
		R _L ≥ 10 kΩ		±12	±13		±12	±13			
√ _{om}	Peak output voltage	$R_L \ge 2 \ k\Omega$	25°C	±11.5	±12.8		±11.5	±12.8		v	
V OM	reak ouiput voltage	R _L ≥1 kΩ			±12			±12			
		$R_L \ge 2 k\Omega$	0°C to 70°C	±11	±12.6		±11	±12.6			
	Large-signal differential	V_{CC} = 15 V, V_{O} = 1.4 V to 11.4 V, R_{L} ≥ 500 k Ω	25°C	100	400			400			
A _{VD}	voltage amplification	$V_{\Omega} = \pm 10, R_{I} = 2k\Omega$	25°C	120	400		120	400		V/mV	
		V0 - ±10, KL - 2K2	0°C to 70°C	100	400		100	400			
B ₁	Unity-gain bandwidth		25°C	0.4	0.6		0.4	0.6		MHz	
ĥ	Input resistance		25°C	8	33		7	31		MΩ	
CMRR	Common-mode	$V_{IC} = \pm 13 \text{ V}, \text{ R}_{S} = 50\Omega$	25°C	100	120		94	110		dB	
	rejection ratio	VIC - ±10 V, IQ - 5022	0°C to 70°C	97	120		94	106		aв	
<svs< td=""><td>Supply-voltage sensitivity</td><td>$V_{CC+} = \pm 3 \text{ V}$ to $\pm 18 \text{ V}$, $R_S = 50\Omega$</td><td>25°C</td><td></td><td>7</td><td>32</td><td></td><td>7</td><td>32</td><td>μV/V</td></svs<>	Supply-voltage sensitivity	$V_{CC+} = \pm 3 \text{ V}$ to $\pm 18 \text{ V}$, $R_S = 50\Omega$	25°C		7	32		7	32	μV/V	
` 5V5	$(\Delta V_{IO} / \Delta V_{CC})$	$v_{UU+} = \pm 5$ v to ± 10 v, $t_{S} = 5002$	0°C to 70°C		10	51		10	51	μν/ν	
PD	Power dissipation	$V_{O} = 0$, No load	25°C		80	150		80	150	mW	
U D		$V_{CC+} = \pm 3 \text{ V}, \text{ V}_{O} = 0, \text{ No load}$	20 0		4	8		4	8	IIIVV	

(1) Since long-term drift cannot be measured on the individual devices prior to shipment, this specification is not intended to be a warranty. It is an engineering estimate of the averaged trend line of drift versus time over extended periods after the first 30 days of operation.

(2) (3) All characteristics are measured with zero common-mode input voltage, unless otherwise specified.

The package thermal impedance is calculated in accordance with JESD 51-7.

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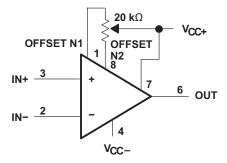


Operating Characteristics

at specified free-air temperature, V_{CC} = 5 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS ⁽¹⁾	OP07C	OP07D	UNIT
	PARAMETER	TEST CONDITIONS ⁽⁷⁾	ТҮР	TYP	UNIT
		f = 10 Hz	10.5	10.5	
Vn	Input offset voltage	f = 100 Hz	10.2	10.3	nV/√Hz
		f = 1 kHz	9.8	9.8	
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 10 Hz	0.38	0.38	μV
		f = 10 Hz	0.35	0.35	
In	Equivalent input noise current	f = 100 Hz	0.15	0.15	nV/√Hz
		f = 1 kHz	0.13	0.13	
I _{N(PP)}	Peak-to-peak equivalent input noise current	f = 0.1 Hz to 10 Hz	15	15	pА
SR	Slew rate	$R_L \ge 2 k\Omega$	0.3	0.3	V/µs

(1) All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise noted.



APPLICATION INFORMATION

Figure 1. Input Offset-Voltage Null Circuit



REVISION HISTORY

CI	hanges from Revision E (May 2004) to Revision F	Pag	е
•	Updated document to new TI data sheet format - no specification changes.		1
•	Deleted Ordering Information table.		1



21-Jan-2014

PACKAGING INFORMATION

Orderable Device		Package Type	•	Pins	•		Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
OP-07DPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP-07D	Samples
OP-07DPSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP-07D	Samples
OP-07DPSRG4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP-07D	Samples
OP07CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07C	Samples
OP07CDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07C	Samples
OP07CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07C	Samples
OP07CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	0 to 70	OP07C	Samples
OP07CDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07C	Samples
OP07CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07C	Samples
OP07CP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	OP07CP	Samples
OP07CPE4	ACTIVE	PDIP	Ρ	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	OP07CP	Samples
OP07DD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07D	Samples
OP07DDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07D	Samples
OP07DDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07D	Samples
OP07DDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07D	Samples
OP07DDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07D	Samples
OP07DDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	OP07D	Samples



21-Jan-2014

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
OP07DP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	OP07DP	Samples
OP07DPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	OP07DP	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

21-Jan-2014

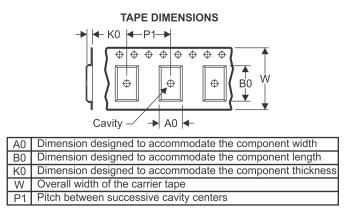
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OP-07DPSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
OP07CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OP07CDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OP07DDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

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PACKAGE MATERIALS INFORMATION

18-Apr-2014



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OP-07DPSR	SO	PS	8	2000	367.0	367.0	38.0
OP07CDR	SOIC	D	8	2500	340.5	338.1	20.6
OP07CDRG4	SOIC	D	8	2500	340.5	338.1	20.6
OP07DDR	SOIC	D	8	2500	340.5	338.1	20.6

P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

PS (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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